

# Standard Rectifier Module

**V<sub>RRM</sub>** = 2x 1400 V

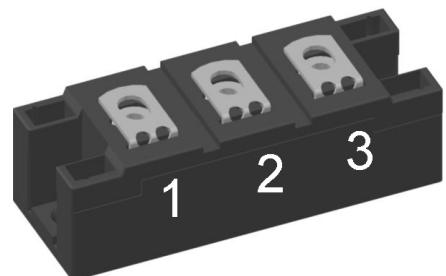
**I<sub>FAV</sub>** = 190 A

**V<sub>F</sub>** = 0.96 V

## Phase leg

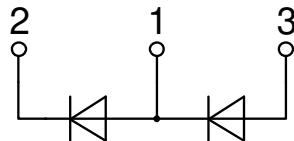
### Part number

**MDD172-14N1**



Backside: isolated

 E72873



### Features / Advantages:

- Package with DCB ceramic
- Improved temperature and power cycling
- Planar passivated chips
- Very low forward voltage drop
- Very low leakage current

### Applications:

- Diode for main rectification
- For single and three phase bridge configurations
- Supplies for DC power equipment
- Input rectifiers for PWM inverter
- Battery DC power supplies
- Field supply for DC motors

### Package: Y4

- Isolation Voltage: 3600 V~
- Industry standard outline
- RoHS compliant
- Soldering pins for PCB mounting
- Base plate: DCB ceramic
- Reduced weight
- Advanced power cycling

### Disclaimer Notice

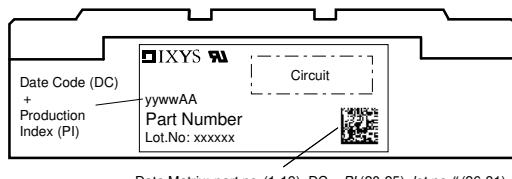
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**Rectifier**

Symbol	Definition	Conditions	Ratings			
			min.	typ.	max.	
$V_{RSM}$	max. non-repetitive reverse blocking voltage	$T_{VJ} = 25^\circ\text{C}$			1500	V
$V_{RRM}$	max. repetitive reverse blocking voltage	$T_{VJ} = 25^\circ\text{C}$			1400	V
$I_R$	reverse current	$V_R = 1400 \text{ V}$ $V_R = 1400 \text{ V}$	$T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = 150^\circ\text{C}$		1 20	mA
$V_F$	forward voltage drop	$I_F = 150 \text{ A}$ $I_F = 300 \text{ A}$ $I_F = 150 \text{ A}$ $I_F = 300 \text{ A}$	$T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = 125^\circ\text{C}$		1.07 1.22 0.96 1.16	V
$I_{FAV}$	average forward current	$T_C = 100^\circ\text{C}$	$T_{VJ} = 150^\circ\text{C}$		190	A
$I_{F(RMS)}$	RMS forward current	180° sine			300	A
$V_{FO}$	threshold voltage	$\left. \begin{array}{l} \text{slope resistance} \\ \end{array} \right\} \text{for power loss calculation only}$	$T_{VJ} = 150^\circ\text{C}$		0.80	V
$r_F$	slope resistance				0.8	$\text{m}\Omega$
$R_{thJC}$	thermal resistance junction to case				0.21	K/W
$R_{thCH}$	thermal resistance case to heatsink			0.08		K/W
$P_{tot}$	total power dissipation		$T_C = 25^\circ\text{C}$		600	W
$I_{FSM}$	max. forward surge current	$t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}$ $t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{sine}$	$T_{VJ} = 45^\circ\text{C}$ $V_R = 0 \text{ V}$		6.60 7.13	kA
		$t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}$ $t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{sine}$	$T_{VJ} = 150^\circ\text{C}$ $V_R = 0 \text{ V}$		5.61 6.06	kA
$I^2t$	value for fusing	$t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}$ $t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{sine}$	$T_{VJ} = 45^\circ\text{C}$ $V_R = 0 \text{ V}$		217.8 211.5	$\text{kA}^2\text{s}$
		$t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}$ $t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{sine}$	$T_{VJ} = 150^\circ\text{C}$ $V_R = 0 \text{ V}$		157.4 152.8	$\text{kA}^2\text{s}$
$C_J$	junction capacitance	$V_R = 400 \text{ V}; f = 1 \text{ MHz}$	$T_{VJ} = 25^\circ\text{C}$	238		pF

**Package Y4**

Conditions			min.	typ.	max.	Unit
$I_{RMS}$	<i>RMS current</i>	per terminal			300	A
$T_{VJ}$	<i>virtual junction temperature</i>		-40		150	°C
$T_{op}$	<i>operation temperature</i>		-40		125	°C
$T_{stg}$	<i>storage temperature</i>		-40		125	°C
<b>Weight</b>				150		g
$M_D$	<i>mounting torque</i>		2.25		2.75	Nm
$M_T$	<i>terminal torque</i>		4.5		5.5	Nm
$d_{Spp/App}$	<i>creepage distance on surface / striking distance through air</i>		<i>terminal to terminal</i>	14.0	10.0	mm
$d_{Spb/Apb}$			<i>terminal to backside</i>	16.0	16.0	mm
$V_{ISOL}$	<i>isolation voltage</i>	$t = 1 \text{ second}$ $t = 1 \text{ minute}$	50/60 Hz, RMS; $I_{ISOL} \leq 1 \text{ mA}$		3600 3000	V V



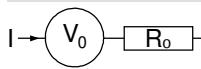
Data Matrix: part no. (1-19), DC + PI (20-25), lot.no.# (26-31), blank (32), serial no.#(33-36)

Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	MDD172-14N1	MDD172-14N1	Box	6	429716

**Equivalent Circuits for Simulation**

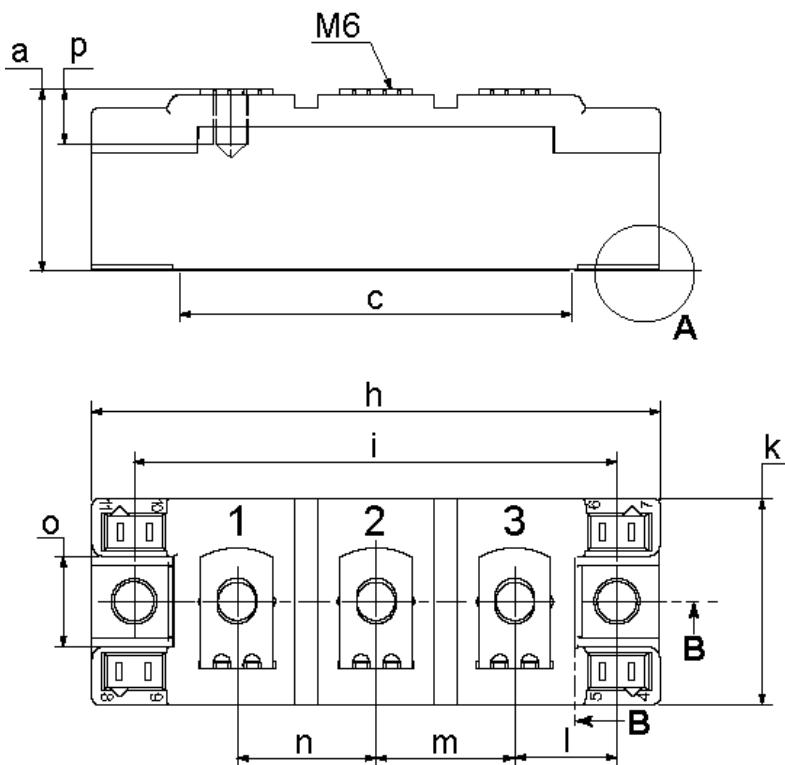
\* on die level

$T_{VJ} = 150^\circ\text{C}$



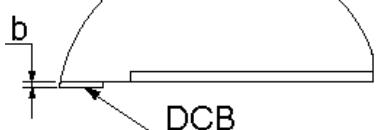
Rectifier

$V_{0\max}$  threshold voltage 0.8 V  
 $R_{0\max}$  slope resistance \* 0.4 mΩ

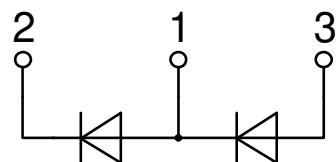
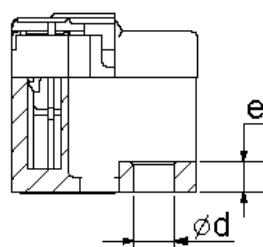
**Outlines Y4**


Dim.	MIN [mm]	MAX [mm]	MIN [inch]	MAX [inch]
a	30.0	30.6	1.181	1.205
b	typ. 0.25		typ. 0.010	
c	64.0	65.0	2.520	2.559
d	6.5	7.0	0.256	0.275
e	4.9	5.1	0.193	0.201
h	93.5	94.5	3.681	3.720
i	79.5	80.5	3.130	3.169
k	33.4	34.0	1.315	1.339
l	16.7	17.3	0.657	0.681
m	22.7	23.3	0.894	0.917
n	22.7	23.3	0.894	0.917
o	14.0	15.0	0.551	0.591
p	typ. 10.5		typ. 0.413	

A (3:1)



B-B (1:1)



## Rectifier

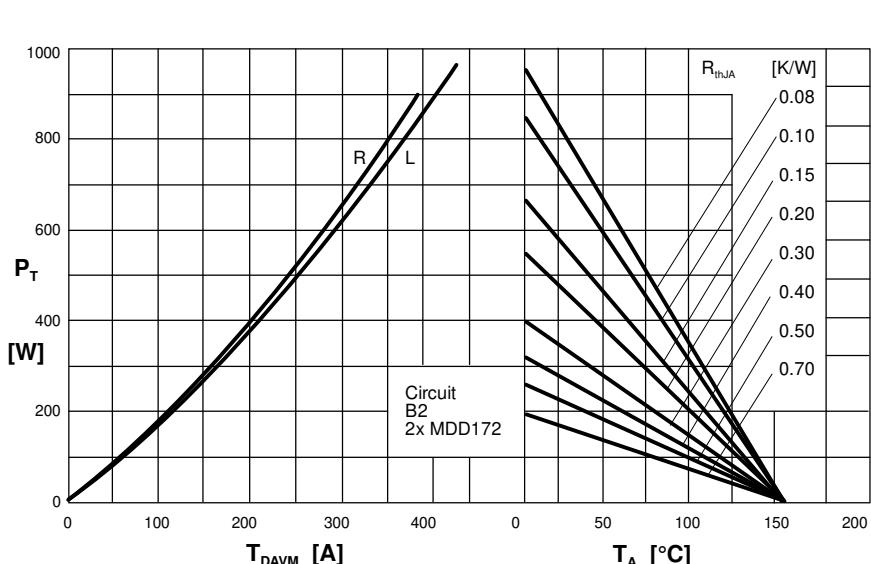
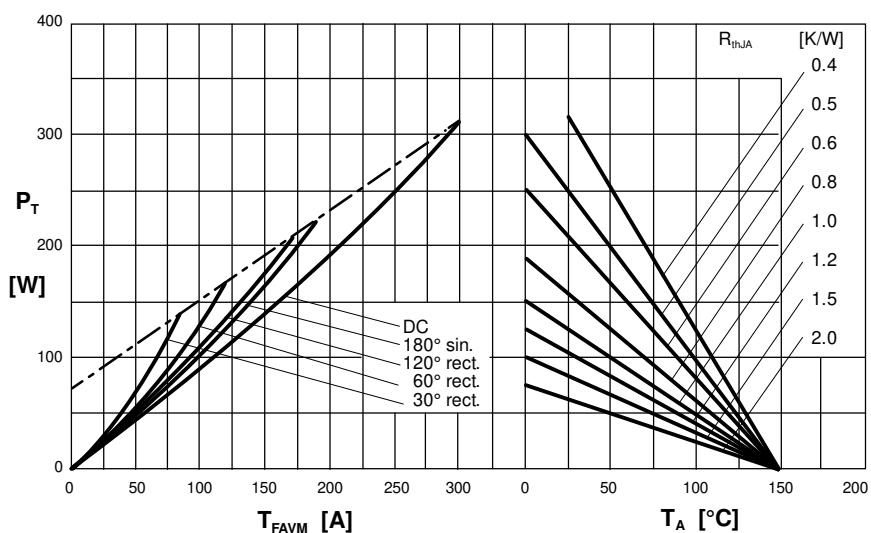
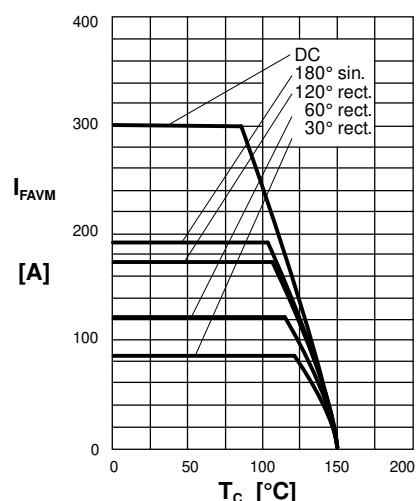
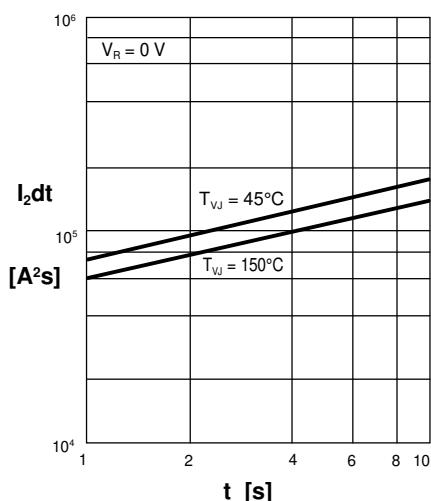
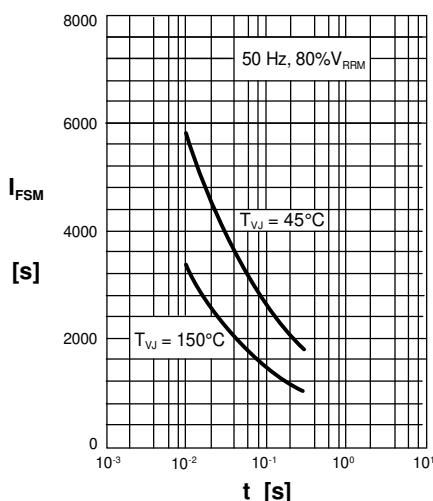


Fig. 4 Single phase rectifier bridge: Power dissipation vs. direct output current and ambient

## Rectifier

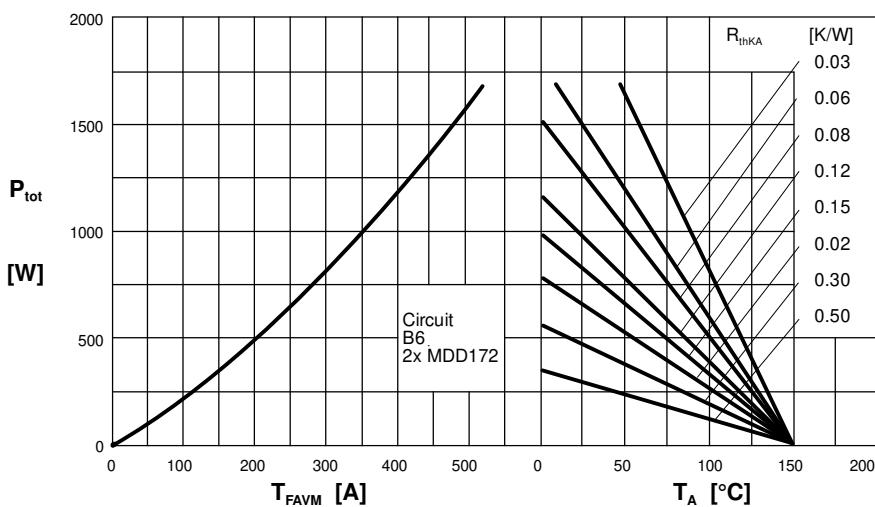


Fig. 5 Three phase rectifier bridge: Power dissipation vs. direct output current and ambient temperature

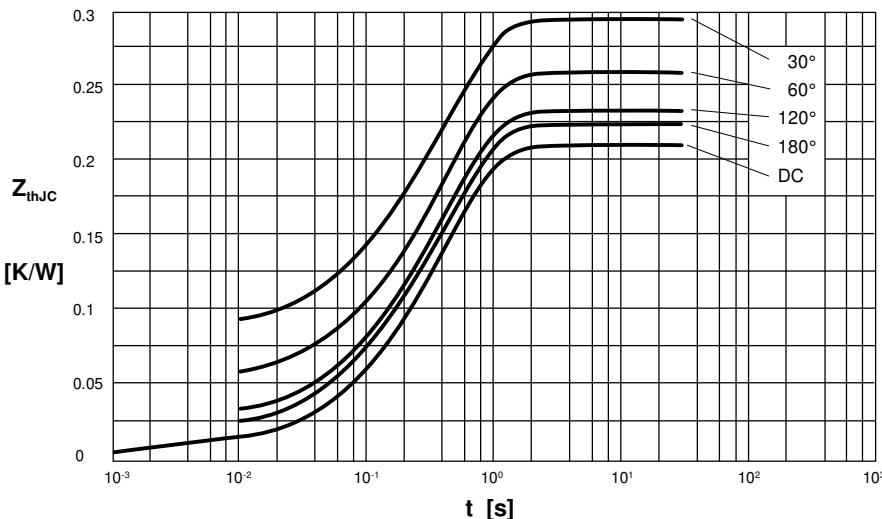


Fig. 6 Transient thermal impedance junction to case (per diode)

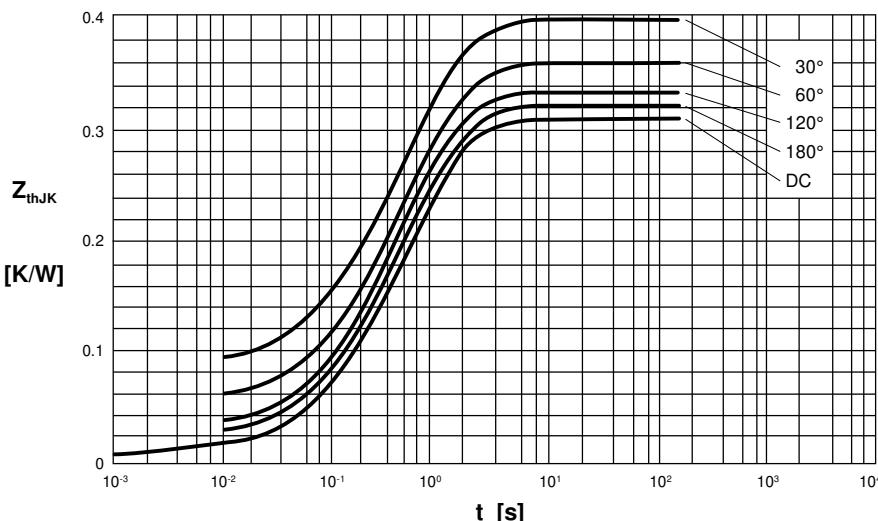


Fig. 7 Transient thermal impedance junction to heatsink (per diode)

$R_{thJC}$  for various conduction angles d:

d	$R_{thJC}$ [K/W]
DC	0.210
180°	0.223
120°	0.233
60°	0.260
30°	0.295

Constants for  $Z_{thJC}$  calculation:

i	$R_{thi}$ [K/W]	$t_i$ [s]
1	0.0087	0.001
2	0.0163	0.065
3	0.1850	0.400

$R_{thJK}$  for various conduction angles d:

d	$R_{thJK}$ [K/W]
DC	0.310
180°	0.323
120°	0.333
60°	0.360
30°	0.395

Constants for  $Z_{thJK}$  calculation:

i	$R_{thi}$ [K/W]	$t_i$ [s]
1	0.0087	0.001
2	0.0163	0.065
3	0.1850	0.400
4	0.1000	1.290